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_	3	sense adj capacitor and cylindrical and silicon adj nitride and silicon adj oxide	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/09/04 00:18
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-	0	inductive adj capacitor and cylindrical and silicon adj nitride	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/08/05 15:27
-	О	inductive adj capacitor and cylindrical and silicon	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/08/05 15:27
_	9	inductive adj capacitor and cylindrical	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/08/05
_	1	inductive adj capacitor and silicon adj nitride	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/08/05 15:34
<del>-</del>	8	inductive adj capacitor and via and silicon	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/08/05
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-	1	inductive adj capacitor and nitride	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/08/11 20:38
-	9	inductive adj capacitor and cylindrical	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/08/11 20:39

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-	2	inductive adj capacitor and silicon with oxide	USPAT; US-PGPUB;	2002/08/11
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_	358	plug and sleeve and inductor and	IBM_TDB USPAT;	2002/08/11
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		adj material	EPO; JPO; DERWENT;	
_	30	plug and sleeve and inductor and storage	IBM_TDB USPAT;	2002/08/11
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		adj capacitor and silicon	US-PGPUB; EPO; JPO;	21:29
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_	181	inductor same storage adj capacitor and	IBM_TDB USPAT;	2002/08/11
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		Silicon and Cyllical and memory	EPO; JPO;	21.31
		industry some storage add somewhere and	DERWENT; IBM_TDB	2002/09/11
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-	19	inductor same storage adj capacitor and	IBM_TDB USPAT;	2002/08/11
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_	8	inductor same storage adj capacitor and silicon and cylindrical and dielectric	USPAT; US-PGPUB;	2002/08/11 21:33
		,	EPO; JPO; DERWENT;	
_	0	stern-donald.in.	IBM_TDB USPAT;	2002/08/11
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			DERWENT; IBM TDB	
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-	41	stern-donald-s.in.	USPAT; US-PGPUB; EPO; JPO;	2002/08/11 22:07
			DERWENT; IBM TDB	
-	829	inductor with capacitor with parallel and silicon	USPAT; US-PGPUB; EPO; JPO;	2002/08/11 22:08
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_	96	inductor with capacitor with parallel and silicon and (cylindrical or sleeve)	USPAT; US-PGPUB; EPO; JPO; DERWENT;	2002/08/11 22:12
-	6	inductor with capacitor with parallel and silicon and (cylindrical or sleeve) and storage adj capacitor	IBM_TDB USPAT; US-PGPUB; EPO; JPO;	2002/08/28 20:59
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_	0	inductor with capacitor with parallel and silicon and (cylindrical or sleeve) and storage adj capacitor and sensor adj capacitor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/08/11 22:14
	0	inductor with capacitor with parallel and silicon and storage adj capacitor and sensor adj capacitor	USPAT; US-PGPUB; EPO; JPO; DERWENT;	2002/08/11 22:14
-	4	inductor same capacitor same parallel and silicon and storage adj capacitor and sensor adj capacitor	IBM_TDB USPAT; US-PGPUB; EPO; JPO;	2002/08/11 22:14
-	1	inductor with capacitor with parallel and silicon and (cylindrical or sleeve) and storage adj capacitor and dielectric	DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO;	2002/08/11 22:19
			DERWENT; IBM TDB	
_	0	plug and capacitor and silicon adj nitride and silicon adj oxide and cvd and etch and trap adj material	USPAT; US-PGPUB; EPO; JPO; DERWENT;	2002/08/28 21:08
_	17	plug and capacitor and silicon adj nitride and silicon adj oxide and cvd and etch and trap	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2002/08/28 21:33
_	17	plug and capacitor and silicon adj nitride and silicon adj oxide and cvd and (inductance or inductor) and memory	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2002/08/28 22:11
-	6	capacitor and first with metal and second with silicon and third with silicon adj dioxide and fourth with silicon adj nitride and plug with metal	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2002/08/28 22:18
-	108	capacitor and silicon and silicon adj dioxide and silicon adj nitride and piezoelectric and memory	IBM_TDB USPAT; US-PGPUB; EPO; JPO;	2002/08/28 22:24
-	170	capacitor and silicon and silicon adj dioxide and silicon adj nitride and (piezoelectric or ferroelectric same	DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO;	2002/08/28 22:24
		plug) and memory	DERWENT; IBM_TDB	

-	70	capacitor and silicon and silicon adj	USPAT;	2002/08/28
		dioxide and silicon adj nitride and	US-PGPUB;	22:29
		((piezoelectric or ferroelectric) same	EPO; JPO;	
		plug) and memory	DERWENT;	
	_	l , , , , , , , , , , , , , , , , , , ,	IBM_TDB	0000 (00 (00
-	1	,	USPAT;	2002/08/28
		dioxide and silicon adj nitride and	US-PGPUB;	22:26
		((piezoelectric or ferroelectric) same	EPO; JPO;	
		plug) and memory and cylind\$6	DERWENT;	
_	0	ganagitar and giligan and giligan adi	IBM_TDB USPAT;	2002/08/28
-	1	capacitor and silicon and silicon adj dioxide and silicon adj nitride and	USPAI; US-PGPUB;	2002/08/28
	į.	((piezoelectric or ferroelectric) same	EPO; JPO;	22:21
		plug) and memory and cylindrical	DERWENT;	
1	İ	prug, and memory and cyrindricar	IBM TDB	
_	1	capacitor and silicon and silicon adj	USPAT;	2002/08/28
	_	dioxide and silicon adj nitride and	US-PGPUB;	22:30
	•	((piezoelectric or ferroelectric) same	EPO; JPO;	
		plug) and memory and (inductor or	DERWENT;	
		inductance)	IBM TDB	
_	1	"6030866".PN.	USPAT	2002/08/28
	_		*******	22:29
-	70	capacitor and silicon and silicon adj	USPAT;	2002/08/28
		dioxide and silicon adj nitride and	US-PGPUB;	22:30
		((piezoelectric or ferroelectric) same	EPO; JPO;	
		plug) and memory	DERWENT;	
1		<u>-</u>	IBM TDB	
-	0	sense adj capacitor and trap adj material	USPAT;	2002/09/03
			US-PGPUB;	17:22
			EPO; JPO;	
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-	10	capacitor and trap adj material	USPAT;	2002/09/03
			US-PGPUB;	17:25
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	2733		USPAT;	2002/09/03
		dielectric	US-PGPUB;	17:27
		•	EPO; JPO;	
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	2233	inductor and semiconductor and	IBM_TDB USPAT;	2002/00/03
-	2233		US-PGPUB;	2002/09/03 17:27
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			DERWENT;	
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		dielectric and sense adj capacitor	US-PGPUB;	17:31
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			IBM_TDB	
-	20	solid adj state same inductor and	USPĀT;	2002/09/03
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-	3	"6249039"	USPAT;	2002/09/04
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_	1	"6249039".PN.	USPAT	2002/09/04
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1 -	1	"6240622".PN.	USPAT	2002/09/04
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-	1	"6069397".PN.	USPAT	2002/09/04
_	1	"6054750".PN.	USPAT	00:19 2002/09/04
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_	1	"5956073".PN.	USPAT	2002/09/04
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10	5	"6486529"	USPAT;	23:50 2004/09/30
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			DERWENT; IBM TDB	
9	8	(("6,346,741") or ("6,054,750") or	USPAT;	2004/09/30
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8	5	((257/531).CCLS.) and ((257/532).CCLS.)	USPAT;	2004/09/30
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